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Ż. U. Borisova, V.			
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REGION OF GLASS FORMATION IN THE SYSTEM ARSENIC-SELENIUM-TELLURIUM

By: Z. U. Borisova, V. R. Panus, and A. A. Obraztsey

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* ye initially, after vowels, and after b, b; e elsewhere. When written as ë in Russian, transliterate as yë or ë. The use of diacritical marks is preferred, but such marks may be omitted when expediency dictates.

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REGION OF GLASS FORMATION IN THE SYSTEM ARSENIC-SELENIUM-TELLURIUM

Z. U. Borisova, V. R. Panus, and A. A. Obraztsov

The highest capacity for glass formation with oxygen analogs is found in elements of groups IV and V of the third and fourth periods of the Periodic System. Combination of these elements leads to the formation of directed paired-electron bonds. Substantial regions of glass formation are obtained when arsenic is combined with sulfur or with selenium and also in the threecomponent system As-S-Se [1]. When the components in the alloys are replaced with their analogs, standing lower in the Periodic System, the ability of the alloys to form glass is reduced due to the rise in the so-called "metallization" of the chemical bonds. Thus, in the arsenic-tellurium system only alloys of the compositions AsTe and AsTe_{0.8} are obtained in conditions of hardening in air [2], while with more severe hardening an alloy of the composition As₂Te₃ is obtained in the glassy state [3].

With an increase in the number of components in the alloys their ability to form glass is raised; the number of spatially different structural units, which increases in this case, hampers the separation of definite crystalline phases. In this connection we might expect that in alloys of three-component systems containing

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tellurium the ability to form glass would be higher as compared with binary systems. Actually, comparatively large regions of glass formations are obtained in the systems As-Si-Te [4] and As-Ge-Te [2].

The region of glass formation in the complex system $As_2S_3^-As_2Se_3^-As_2Te_3$ was determined in work [5]. In work [6] it was shown that alloys with compositions from As_2Se_3 to $As_2Se_3^{-4}As_2Te_3$ can be obtained in the vitreous state along the section $As_2Se_3^-As_2Te_3^-As_3$

This work involves determination of the region of glass formation in the system As-Se-Te. To determine the region of glass formation in this system and also for subsequent investigation of the physicochemical properties of glasses of this system we synthesized alloys of 45 compositions (see table).

The alloys were synthesized by vacuum melting from elemental arsenic, tellurium of mark V-3, and selenium of rectifier grade.. Ampules with the charge were heated to 700°C in the course of 3-4 hours and held at this temperature for an hour. Then the temperature was raised to 950°C and the ampules with the melt were held for 5 hours with application of vibration mixing. The melts were cooled by pulling the ampules out of the furnace into the air (air hardening: 950°C 5 min 20°C). For certain compositions the specimens from parallel melts were synthesized in the flame of a gas-oxygen burner. The properties of the alloys obtained in the two different synthesis conditions were identical within the limits of measurement error.

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As the initial materials during synthesis of alloys of the system As-Se-Te we took determined compositions in the As-Se system which were investigated in work [7]; in these compositions selenium was progressizely substituted by tellurium. The content of arsenic remains constant.

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Table. Data from research on the system As-Se-Te.								
(1) Xi ', m	Seremanne () (2) *****	3) Caseponnie at. 4.			X - (Se+ + Te)		Масросы р- заснь (11), 42° я я ³	(6) Ilpaccine
		3		5	6	7	•	9
1	AsSecto Train	ō2,5	30,0	75		+,673	113	Стекло
23	AsSec Tear	62,5 65 5	22,5 18,7	15,0	ė. O.	5,01	146 171	Ciencio
4	AsSec. Troja.	62,5 62,5	11.2	!5,8 26,3	AsN _{o.ii}	4,957 5,69	161	Cick.in (7) Cick in
ā	A-State for a si	25	75	31,0	~	5,13	142	Cierau
Ű	AsSept. Tegg	125	3,7	33.S		5,371		As Acip As Ster
	eye ya							-1 Clexue (7)
	AsSe _{u,*} [7]			Ì		4.55	65	
7	AsSe Te	55.6	35,5	5,9		4,005	128	Ciesan :
N	AsSept Teger	55,5	24,5	17,5		4,592	142	Стекая
5° -	AsStant Treat	55,9	27:2	22.2	A1Xe.A	4.355	157	Crex20
:0	AsSec. Tes	55.6	133	31,1	え	5,18	163	Ciex20 } {7}
11 12		55,5	59	35,5		5,254 5,355	162 163	Cienzo
•=	AsSector Teers AsTeas [2]	130,0	4,4	40,7		5,421	173	CTCE30 CTCE30
					ļ	1		
:3	Asse [7] Assen, Trag	50,0	149.9	10,0	ĺ	4,53 4,715	139	Cicean Crexan
14	Assecte,	50.0	30.9	23.9	ļ	4.918	145	Cter:4
15	Assesse	50,0	2.0	250	• ×	5.025	156	Ciezap
16	Asse4]Tray	:00	15,0	35.0		5.7%	100	Ciecap (7)
:7	n-Sc, 2 Irap	60.0	10,0	40,0	1	5.397	164	Cirsan
3	As Caller	56,0	5,9	0ذة	ļ	5,307	165	Circ #20
	AsTe [2]	İ		i		5,453	161	Citsar /
	Ass. [7]		Į			4,55	156	Ctrx30
19	ASSC17-C0.3	49,0	45.6	12,0		4,773	142	Crenso
20	A.S. a. Te. 4	40,9	350	34.9	2	4973	140	Cierse (7)
21 22	Assention To	40,9	3:-0 15.0	33).9 42,9	A1X1.5	5,079 5,269	147	Cresse Cresse
22	ASC, Teig	40,9	12.0	45.9	<	5,371	145	Ches
23	, Stellite		6,0	51.0	1	6 . 63	_	AsaTe, spacial (8)
					Į –	4.53	133	CICEN
3	AsSen [7] AsSen Ten	25,5	57,1	14.3	I	4.783	123	Cicalo
	Assen Te.s	28.6	42.5	216	l	5.013	:30	Course 1
27	AsSer Ter -	23,6	35.7	257	1	5.133	17/	Ctrato (7)
22	AsSel Tels	25.6	21.6	49,E	N S	5,325	125	Cierco
29	ASSCOSIC	28.6	14.3	57,1	٦ آ	5,63	134	Cieszo
- 30	Assent Tezzi	25.6	16.0	61,4		5,5 H		Спекнократным (9)
31	Asterileza	36	1.7	64,3	l	6,165		Ast Ter : Te : + Clean (7)
-	AsSec [7]				ļ	4.65	105	Cirs m
32	Assessie	39.9	619	16.9	1_	4,735	169	Citisso Citasso (77)
5 5		30.0 20.9	47.9	32.6 49,0	N N	5,651 5,126	10j 117	Circaso (7) Circaso
37		72.9	20	4.0	<	5270	122	Cirate
5	AsSel Ters	3:0	24.9	560	1	5,509	-	Те практала (8)
	A.S. [7]			I	I	4.35	6	()
37	Assein	10 <u>.</u> 9	72.9	i5,0	ļ	CH	59	Cieszo (7)

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KEY: (1) No.; (2) Chemical composition; (3) Content, at. \$; (4)
Density (d), g/cm²; (5) Microhardness (H), kg/mm²; (6) Remarks;
(7) Glass; (8) crystal; (9) glass-crystal; (10) Cr. solid solution.

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Table (continued)

1	2	3		3	•	-	3	•
3 6 2	AsSes Tess AsSes Tess AsSes Tess	10,9 10,9 10,0	51,0 45,0 36,9	35,0 45,0 54,0	AsX5	5.015 5,147 5,596	102 107 -	Стекло (7) Стекло (7) Те крастала (8)
년 2 4	A:Sex [7] A:Sex 5 Tex A:Sex 5 Tex A:Sex 7 Tex A:Sex 7 Tex 9	4,8 4,5 4,5	73,8 55,4 46,2	15,5 35,9 45,2	A+X,1	4,2% 47,99 5,0,7 5,4%	52 52 91 -	Ciex 50 Ciex 50 Ciez 50 Ciez 20 Ciez 20 Ciez 20 Ciez 20 Ciez 20 Ciex 50 Ciex 5
44	Seale Seale	0	F9.0 70 <u>.</u> 0	20,0 30,9	×.	4)#14 5,3% 5	76 	Слекор (?) Кр. тэгрэ, растыр (20

The compositions of the obtained vitreous and glass-crystalline alloys, the atomic 1 content of components in them, the total content of chalcogen in the alloys (X), their density, and their microhardness are presented in the table. The composition of separated crystalline phases obtained by X-ray phase analysis is also shown for alloys of the glass-crystal type.

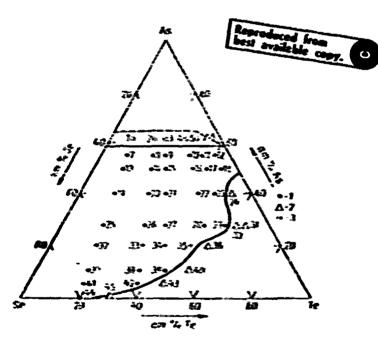


Fig. 1. Glass formation region in the system As-Se-Te. 1 - glass; 2 - glass-crystal; 3 - glass with nonuniform composition.

The compositions of the vitreous and glass-crystalline alloys are plotted in the concentration triangle in Fig. 1 and the region of glass formation in the system As-Se-Te is marked. From Fig. 1 it is clear that replacement of selenium by tellurium facilitates crystallization of the alloyr. However, this tendency toward crystallization in the three-component system As-Se-Te is substantially more weakly expressed than in the binary system As-Te. This is indicated by the large glass-formation region in the As-Se-Te system. Up to 58 at. \sharp tellurium and up to 60 at. \sharp arsenic can be introduced into the composition of the vitreous alloys. As in the As-Se-S system, the glass formation region in the As-Se-Te system is displaced in the concentration triangle toward the side with predominating contents of selenium. and day tupic of a difficulty of

The maximum capacity for glass formation with tellurium is found in alloys with commensurate contents of arsenic and selenium (from $AsSe_{0,3}$ to AsSe). In the selenides which contain 20 at. \sharp or less arsenic the ability to lorm glass with tellurium is noticeably reduced, while up to 20 at. \sharp tellurium can be introduced into the composition of the elementary vitreous selenium; however, a further increase in the tellurium content leads to the formation of crystalline solid solution. The greatest ability to form glass with tellurium in alloys with commensurate contents of arsenic and selenium indicates that selenium is not the only glass-former in this system. The appearance of more complex structural units in the melt also favors glass formation.

In alloys of the composition $AsX_{0.6}$, 33 at. 5 selenium (out of 37.5 at. 5) can be substituted by tellurium. During the synthesis of alloys with the composition $AsX_{0.6}$ the formation of a small encrustation containing crystalline arsenic is observed on the inner surface of the ampule. Thus the actual composition of the obtained vitreous alloys differs from the composition of of the initial charge. Vitreous alloys of indeterminant composition

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are singled out by a broken line in the region of glass formation (Fig. 1).

In agreement with literature data, along the As_2Se_3 - As_2Te_3 (AsX_{1.5}) section 52 at. \$ of the selenium (out of 60 at. \$) is substituted by tellurium. The increased crystallization capacity of the alloys along this section as compared with the AsX_{1.0} and AsX_{2.5} sections is apparently connected with the fact that As_2Se_3 and As_2Te_3 are individual compounds.

Tellurium and the arsenic telluride As_2Te_3 are the basic crystalline phases which can be singled out in glass-crystal and polycrystalline alloys. In the glass-crystalline alloy No. 6, enriched with arsenic, crystalline arsenic is separated. In alloy No. 43, which has a dominant content of chalcogens, it is apparently their solid solutions which are separated.

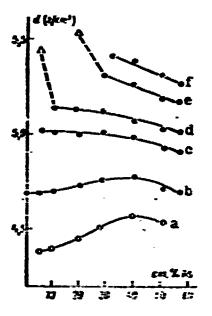


Fig. 2. Nature of the change in density of alloys as a function of the arsenic content. $a - AsSe_x$; b -As $(Se_{0.8}Te_{0.2})_x$; c -As $(Se_{0.6}Te_{0.4})_x$; d -As $(Se_{0.5}Te_{0.5})_x$; e -As $(Se_{0.2}Te_{0.8})_x$; f -As $(Se_{0.2}Te_{0.8})_x$; f -As $(Se_{0.2}Te_{0.8})_x$. Designation: $r/cn^3 = g/cm^3$.

The density of the glasses was measured with a hydrostatic balance; microhardness was measured on the PMT-3. The density of the obtained vitreous alloys is increased linearly with substitution of selenium by tellurium. Crystallization of the alloys is

accompanied by a sharp nonlinear increase in density. In the binary system As-Se the density of the vitreous alloys varies unevenly. The maximum value of density in the As-Se system was obtained for the stoichiometric compound As_2Se_3 (line a on Fig. 2) [7]. As selenium is substituted by tellurium in the vitreous alloys the nature of the change in their density as a function of arsenic content becomes ever smoother, virtually linear (lines b+f, Fig. 2); there is a sharp deviation from linearity for alloys which are partially crystallized.

The microhardness of the glasses in the system As-Se-Te varies within the limits $80-170 \text{ kg/mm}^2$. When selenium is substituted by tellurium in the vitreous alloys of the composition AsX_{1.5}, AsX_{2.5}, and AsX₄ the microhardness remains virtually unchanged. The virtual invariability of microhardness during substitution of selenium by tellurium over the section As₂Se₃-As₂Te₃ was indicated in work [5]. In vitreous alloys enriched both with arsenic (AsX_{0.8}, AsX) and chalcogen (AsX₉, AsX₂₀) the microhardness is increased noticeably as selenium is substituted. by tellurium. The nature of the change in microhardness as a function of arsenic content in vitreous alloys shows virtually no differences from the change in density.

Conclusion

1. The region of glass formation was determined in the system As-Se-Te. It was shown that up to 58 at. \$ tellurium and 50 at. \$ arsenic can be introduced into the composition of the vitreous alloys.

2. The nature of the dependence of density and microhardness of the obtained vitreous alloys on the ratio and content of their components was established.

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